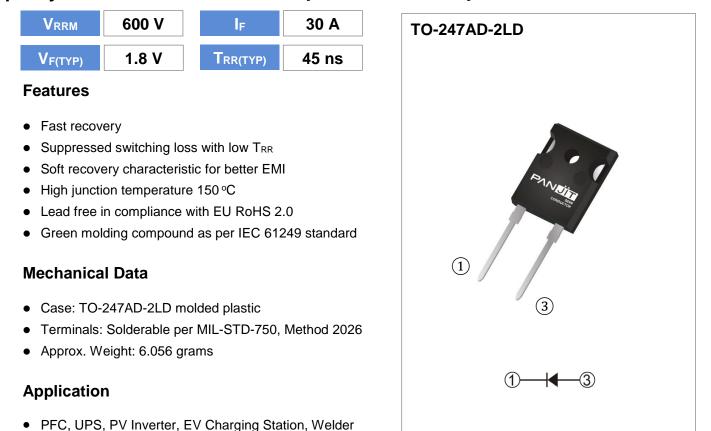


### Speedy Diode - Short Reverse Recovery Time, Fast Recovery Diode



### Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	600	V
DC Blocking Voltage	VDC	600	V
Diode Forward Current @ Tc=115°C	I <sub>F(AV)</sub>	30	А
Repetitive Peak Surge Current <i>tp</i> = 8.3 ms, sine-wave, D=0.5	Ifrm	60	A
Peak Forward Surge Current <i>tp</i> = 8.3 ms, single half sine-wave	I <sub>FSM</sub>	280	A
Maximum Power Dissipation	P <sub>total</sub>	179	W
Operating Junction Temperature Range	TJ	-55~150	°C
Storage Temperature Range	T <sub>STG</sub>	-55~150	°C



## **Electrical Characteristics** ( $T_c = 25$ °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Forward voltage drop	VF	I <sub>F</sub> = 30 A, T <sub>J</sub> = 25 °C	-	1.8	2.3	V	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.45	-		
Reverse leakage current	I <sub>R</sub>	$V_R = 600 V, T_J = 25 °C$	-	-	250	μA	
		V <sub>R</sub> = 600 V, T <sub>J</sub> = 125 °C	-	-	1	mA	
Reverse recovery time		I <sub>F</sub> =0.5A, I <sub>R</sub> =1A,					
		I <sub>RR</sub> =0.25A	-	-	45	ns	
	T <sub>RR</sub>	T <sub>J</sub> = 25 °C					
		$I_F = 1 \text{ A}, V_R = 30 \text{ V},$					
		di/dt = 300 A/µs,	-	-	35	ns	
		T <sub>J</sub> = 25 °C					
Reverse recovery time	T <sub>RR</sub>	$I_F = 30 \text{ A}, V_R = 400 \text{ V},$	-	45	70	ns	
Peak recovery current	IRRM		-	3.6	-	А	
Reverse recovery charge	Qrr	di/dt = 300 A/µs,	-	90	-	nC	
Softness factor = tb / ta	S	T」= 25 °C	-	1.5	-		
Reverse recovery time	T <sub>RR</sub>	$I_F = 30 \text{ A}, V_R = 400 \text{ V},$ di/dt = 300 A/µs,	-	70	-	ns	
Peak recovery current	I <sub>RRM</sub>		-	9.9	-	А	
Reverse recovery charge	Qrr		-	480	-	nC	
Softness factor = tb / ta	S	T」= 125 °C	-	0.3	-		
Thermal Resistance	Rejc		-	-	0.7	°C/W	



# PSDH3060S1



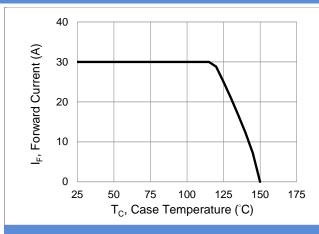
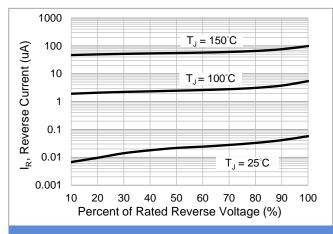
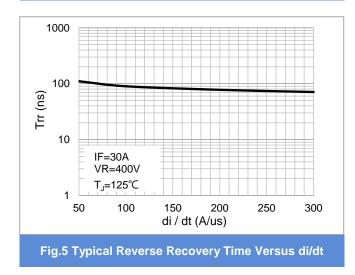


Fig.1 Forward Current Derating Curve



**Fig.3 Typical Reverse Characteristics** 



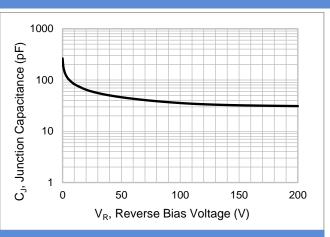
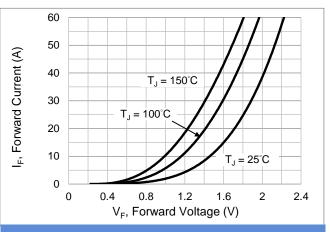


Fig.2 Typical Junction Capacitance



**Fig.4 Typical Forward Characteristics** 

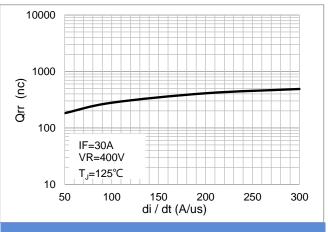


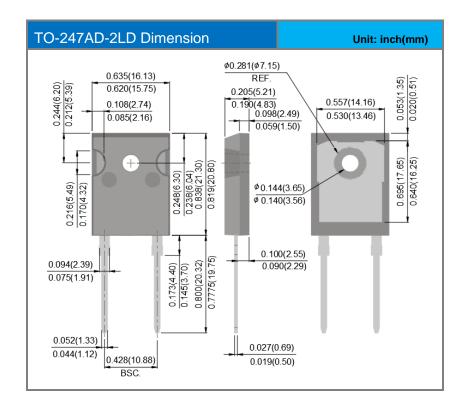
Fig.6 Typical Reverse Recovery Charges Versus di/dt



### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking
PSDH3060S1	TO-247AD-2LD	30pcs / Tube	SDH3060S1

### **Packaging Information**





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